## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 6,949,481 B1

Page 1 of 1

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INVENTOR(S) : Halliyal et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

## Column 6,

Line 29, replace "insulator (SOD) semiconductor" with -- insulator (SOI) semiconductor --.

## Column 18,

Line 33, replace "about 0-1 atomic" with -- about 0.1 atomic --.

Signed and Sealed this

Twenty-second Day of November, 2005

JON W. DUDAS
Director of the United States Patent and Trademark Office